DGG OR DL PACKAGE

(TOP VIEW)

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- Member of the Texas Instruments Widebus™ Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Latch-Up Performance Exceeds 250 mA Per JEDEC Standard JESD-17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

description

This 16-bit transparent D-type latch is designed for 2.7-V to 3.6-V V_{CC} operation.

The SN74LVC16373 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. It can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

48 🛭 1LE 10E 47 1D1 1Q1 **1**2 1Q2 📙 3 46 1D2 GND 4 45 🛮 GND 1Q3 🛮 5 44 🛮 1D3 1Q4 **[**] 6 43 1 1 D4 V_{CC} []7 42 V_{CC} 1Q5 🛮 8 41 1 1D5 1Q6 📙 9 40 1 1D6 GND 110 39 | GND 1Q7 L 11 38 1 1D7 108 Π 12 37 D8 36 2D1 2Q1 **1**13 35 2D2 2Q2 🛮 14 GND II 15 34 | GND 2Q3 🛮 16 33 D3 2Q4 🛮 17 32 2D4 V_{CC} 4 18 31 V_{CC} 2Q5 📙 19 30 D5 2Q6 🛮 20 29 2D6 GND 21 28 | GND 2Q7 🛮 22 27 2D7 2Q8 🛮 23 26 2D8 20E 24 25 2LE

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74LVC16373 is characterized for operation from −40°C to 85°C.



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FUNCTION TABLE (each 8-bit section)

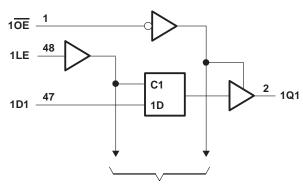
	INPUTS	OUTPUT	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	X	Χ	Z

logic symbol†

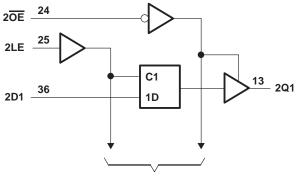
1<u>OE</u> 1EN 48 C3 1LE 24 2OE 2EN 25 2LE C4 47 2 3D 1Q1 1D1 1 ▽ 3 46 1Q2 1D2 5 44 1D3 1Q3 43 6 1Q4 1D4 8 41 1D5 1Q5 40 9 1D6 1Q6 38 11 1D7 1Q7 37 12 1D8 1Q8 36 13 4D 2D1 2 ▽ 2Q1 35 14 2D2 2Q2 16 2D3 2Q3 32 17 2D4 2Q4 30 19 2D5 2Q5 29 20 2D6 2Q6 27 22 2D7 2Q7 23 26 2D8 2Q8

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Channels



To Seven Other Channels



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}		-0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)		-0.5 V to 4.6 V
Output voltage range, VO (see Notes 1 and 2)		V to V_{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)		–50 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)		±50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±50 mA
Continuous current through V _{CC} or GND		±100 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 3):	DGG package	0.85 W
,	DL package	1.2 W
Storage temperature range, T _{stg}		-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. This value is limited to 4.6 V maximum.
 - 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
Vсс	Supply voltage		2.7	3.6	V
VIH	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V_{IL}	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V
٧ _I	Input voltage		0	VCC	V
Vo	Output voltage			VCC	V
lau	High-level output current $ \frac{V_{CC} = 2.7 \text{ V}}{V_{CC} = 3 \text{ V}} $		-12	mA	
ЮН		V _{CC} = 3 V		-24	IIIA
lo.	V _{CC} = 2.7 V			12	mA
IOL	Low-level output current VCC = 3 V			24	IIIA
$\Delta t/\Delta V$	Input transition rise or fall rate		0	10	ns/V
T _A	Operating free-air temperature		-40	85	°C

NOTE 4: Unused control inputs must be held high or low to prevent them from floating.



SN74LVC16373 16-BIT TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	v _{cc} †	MIN	TYP [‡]	MAX	UNIT	
1		$I_{OH} = -100 \mu\text{A}$	MIN to MAX	V _{CC} -0	.2			
		I _{OH} = -12 mA	2.7	2.2			V	
VOH		10H = - 12 111A	3	2.4			v	
		$I_{OH} = -24 \text{ mA}$	3	2				
		I _{OL} = 100 μA	MIN to MAX			0.2		
VOL		I _{OL} = 12 mA	2.7			0.4	V	
		I _{OL} = 24 mA	3			0.55		
IĮ		V _I = V _{CC} or GND	3.6			±5	μΑ	
1.4	Data inputs	V _I = 0.8 V	3	75				
l(hold)	Data iriputs	V _I = 2 V		-75			μΑ	
loz		$V_O = V_{CC}$ or GND	3.6			±10	μΑ	
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6			40	μΑ	
ΔICC		One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	3 V to 3.6 V			500	μΑ	
Ci	·	$V_I = V_{CC}$ or GND	3.3		3.5		pF	
Co		$V_O = V_{CC}$ or GND	3.3		7		pF	

[†] For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		UNIT
		MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high	4		4		ns
t _{su}	Setup time, data before LE \downarrow	2		2		ns
th	Hold time, data after LE↓	2		2		ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	(INPUT) I (OUTPUT) I	V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		UNIT
	(INPOT)		MIN	MAX	MIN	MAX	
^t pd	D	Q	1.5	7		8	ns
	LE		2	8		9	
t _{en}	ŌĒ	Q	1.5	8		9	ns
^t dis	ŌĒ	Q	1.5	7		8	ns

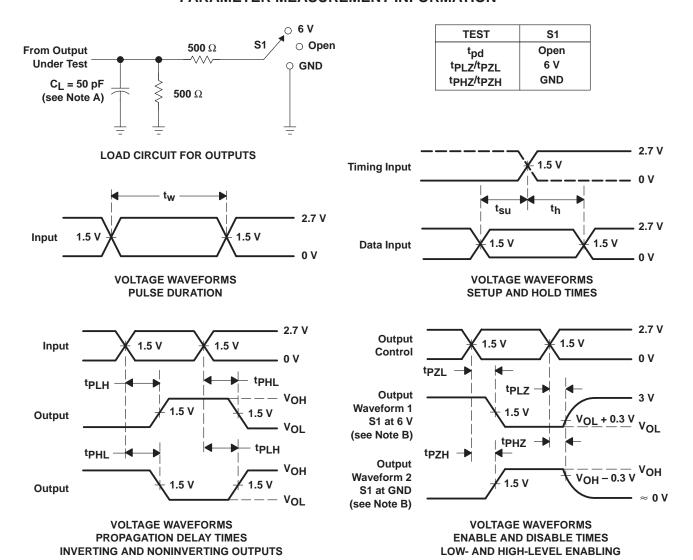
operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	TYP	UNIT	
C .	Power discipation capacitance per latch	Outputs enabled	C ₁ = 50 pF. f = 10 MHz	20	рF
Cpd	Power dissipation capacitance per latch	Outputs disabled	$C_L = 50 \text{ pF}, f = 10 \text{ MHz}$	4	рі



[‡] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpZL and tpZH are the same as ten.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



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